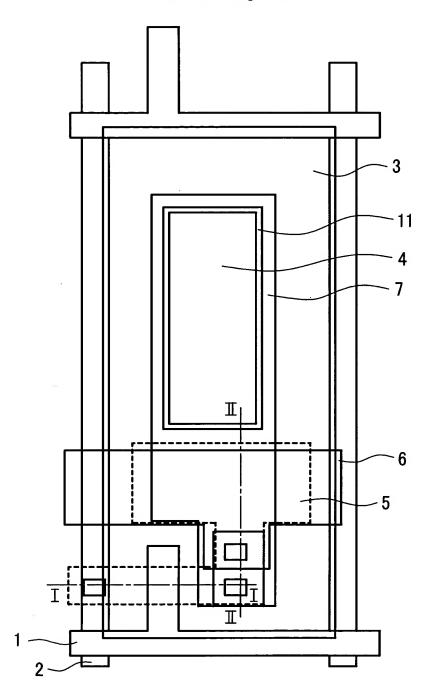
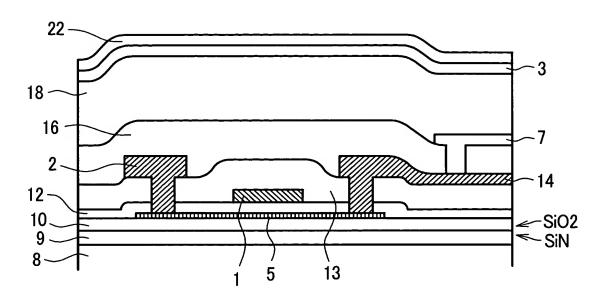
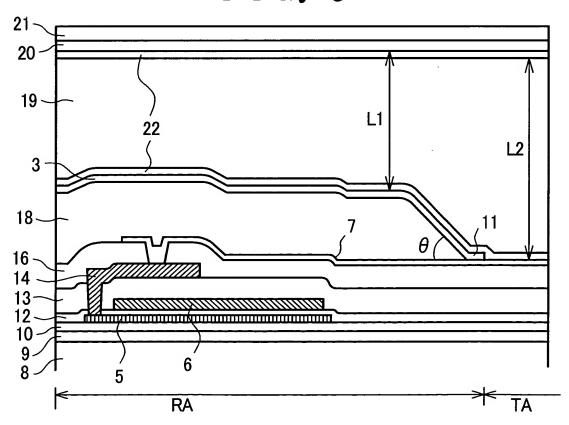
F I G. 1



F I G. 2

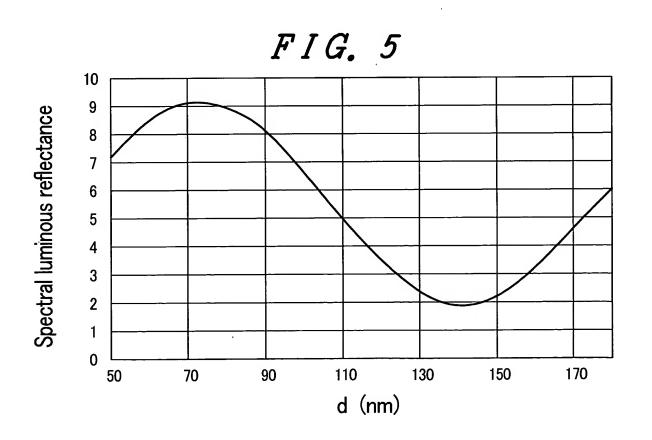


F I G. 3

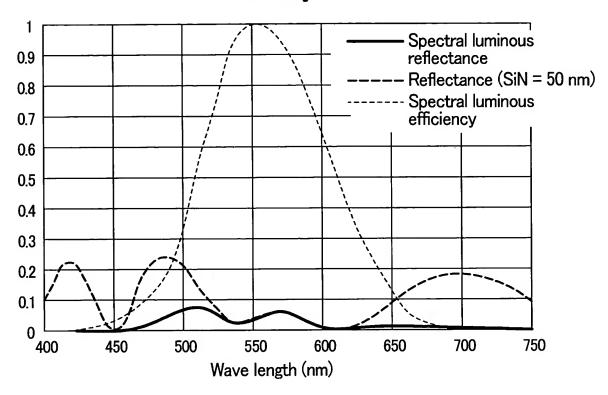


F I G. 4

	Material	d (nm)	n (Wave length : 555nm)
Orientation film/LC	Orientation film/LC		1.5
Transparent electrode	ITO	77	2.0
2nd. insulating film	SiO2	200	2.0
1st. insulating film	SiO2	540	1.5
Gate insulating layer	SiO2	100	1.5
2nd. lower layer	SiO2	100	1.5
1st. lower layer	SiN	50~180	2.0
Substrate	Glass		



F I G. 6



F I G. 7 1 Spectral luminous reflectance 0.9 Reflectance (SiN = 140 nm)8.0 Spectral luminous 0.7 efficiency 0.6 0.5 0.4 0.3 0.2 0.1

600

650

700

550

Wave length (nm)

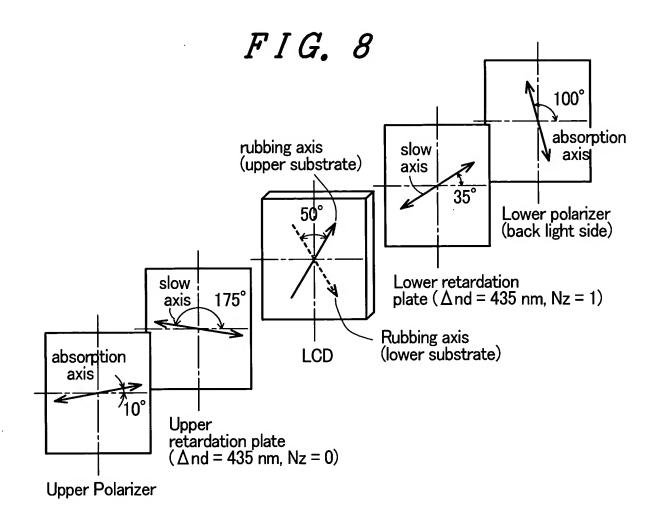
750

0

400

450

500



F I G. 9

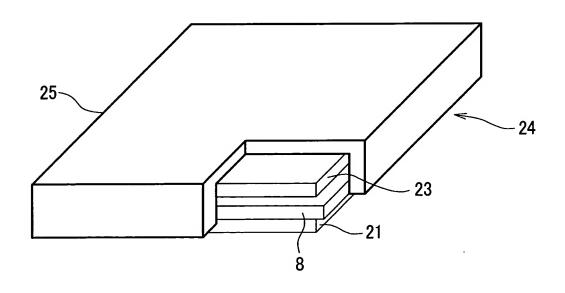


FIG. 10

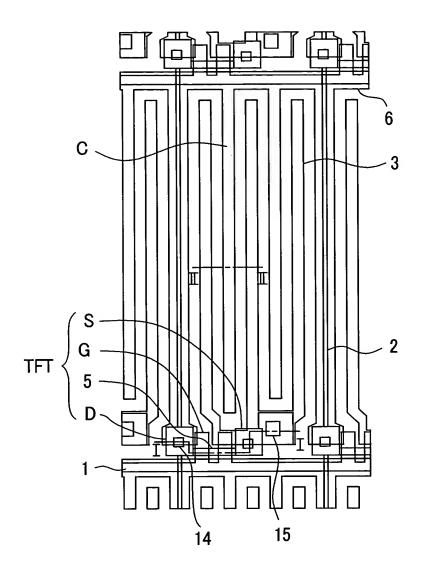


FIG. 11

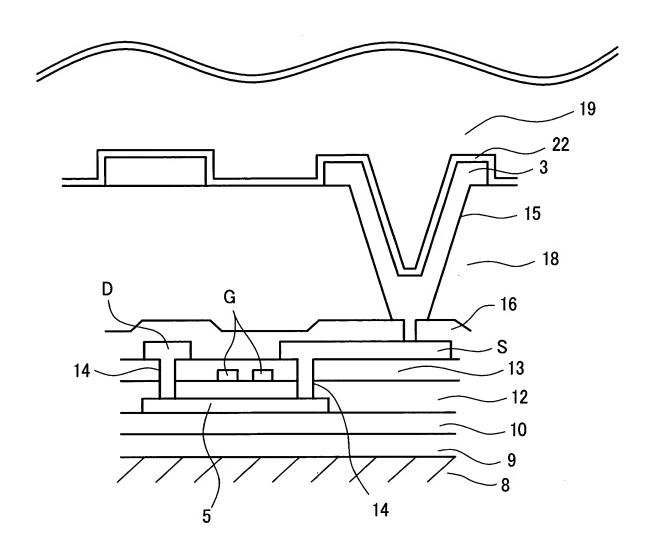


FIG. 12

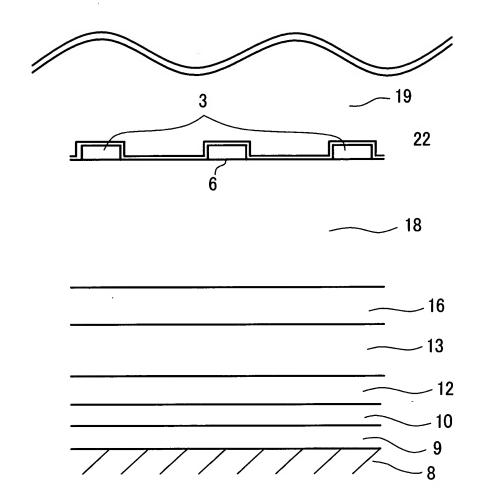


FIG. 13

	Material	d (nm)	n (Wave length : 555nm)
Orientation film/LC	Orientation film/LC	5200	1.5
Transparent electrode	ITO	140	2.0
Passivation film	Organic film	1730	1.6
2nd. insulating film	SiO2	300	1.85
1st. insulating film	SiO2	540	1.5
Gate insulating layer	SiO2	100	1.5
2nd. lower layer	SiO2	100	1.5
1st. lower layer	SiN	150	1.85
Substrate	Glass	,—	1.5

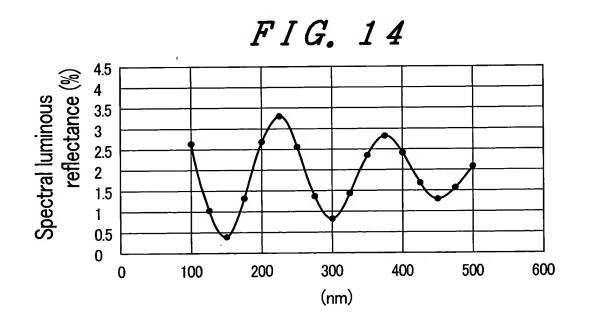
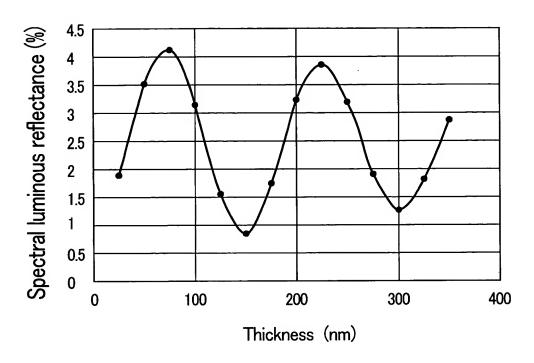
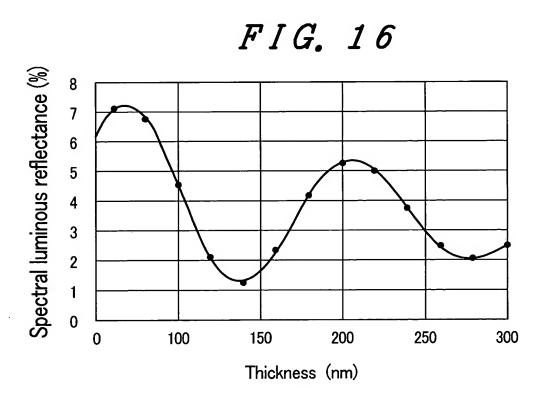
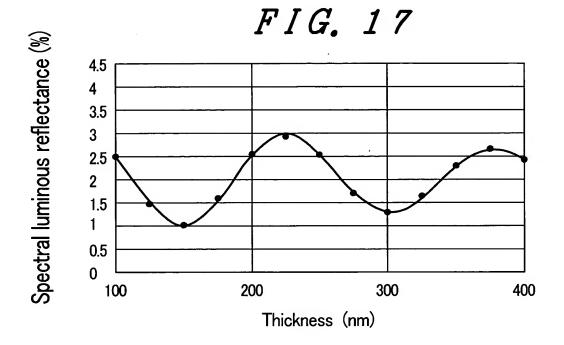


FIG. 15







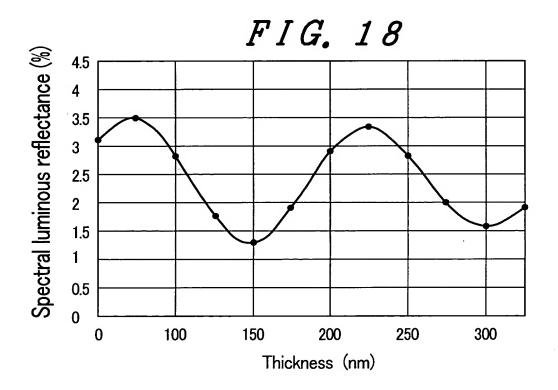


FIG. 19

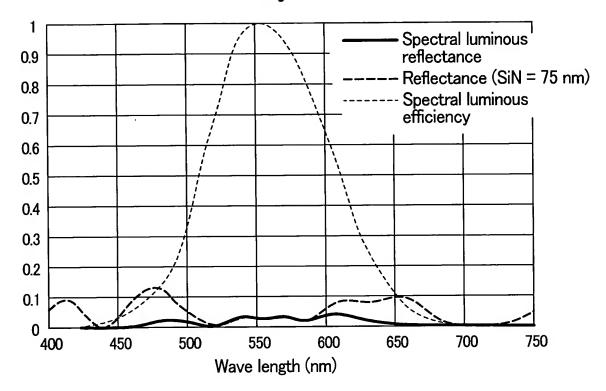


FIG. 20

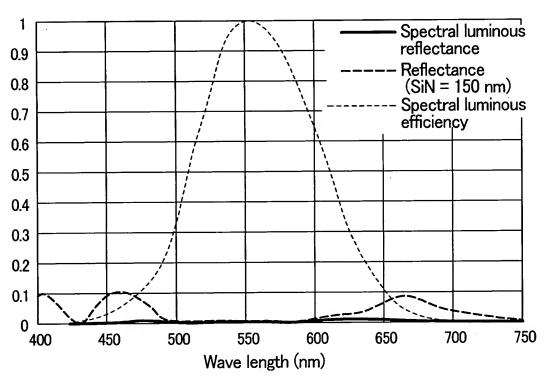


FIG. 21

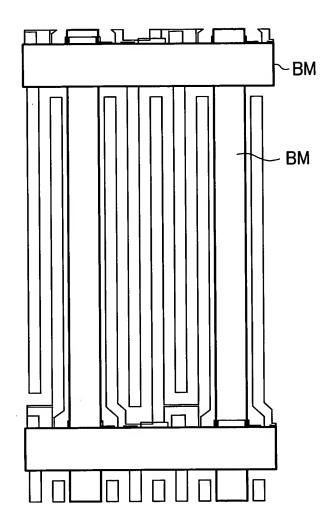
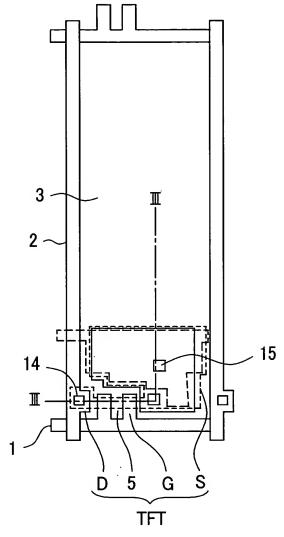


FIG. 22





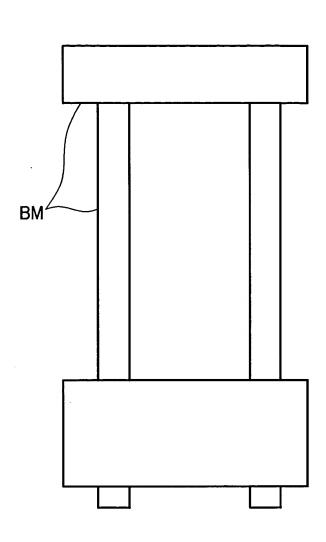


FIG. 24

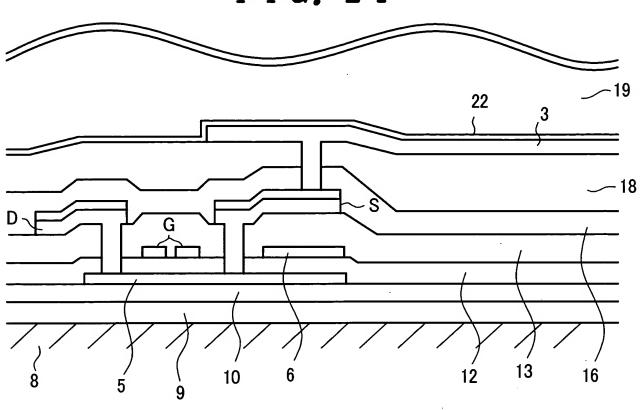


FIG. 25

